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	DI DOMPONIO, CONTOURNO	PAGE 10 Pages
APPROVED BY: DATE: ELECTRONIC COMPONENTS GROUP SHARP CORPORATION		REPRESENTATIVE DIVISION
O. Shhikawa (Gr. 6, 1996	SPECIFICATION	OPTO-ELECTRONIC DEVICES DIV.
DEVI	CE SPECIFICATION FOR	
MOD	PHOTOINTERRUPTER EL No.	
	GP1S93	
	(Specified for THOMSON)	
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3. Please contact and consult	with a Sharp safes representative for any que	_
CUSTOMER'S APPROV	DATE PRESENT BY	iger. t. 1996 ED L. Eleina
DATE	Opto-	Managerof -System Project Team
ВУ	Opto ELEC	-Électronic Devices Div. COM Group RP CORPORATION

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1. Application

This specification applies to the outline and characteristics of transmissive type photointerrupter; Model No. GP 1 S93.

2. Outline

Refer to the attached drawing No. CY755 1i02.

3. Ratings and characteristics

Refer to the attached sheet, Page 4 to 6.

4. Reliability

Refer to the attached sheet, Page 7.

5. Incoming inspection

Refer to the attached sheet, Page 8.

6. Supplements

6.1 parts

Refer to the attached sheet, Page 9.

6.2 Packing

Refer to the attached drawing No. SOE99 1548

7. Notes

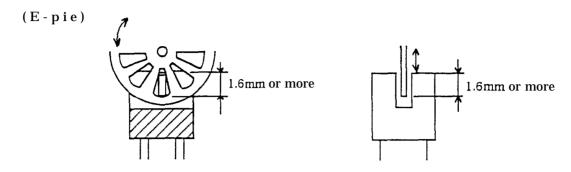
1) In circuit designing, make allowance for the degradation of the light emitting diode output that results from long continuous operation.

(MAX.: 50% degradation/5 years)

2) To prevent photointerrupter from faulty operation caused by external light, do not set the detecting face to the external light.

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3) Opaque board shall be installed at place $1.6 \mathrm{mm}$ or more from the top of elements,



- 4) To solder onto lead pins, solder at the position of 1 mm or more from the package's bottom at 260 'C for 5 s or less. Please don't bend lead pins from the root of package when soldering. And take please care not to let any external force exert on lead pins. Please don't do soldering with preheating, and please don't do soldering by reflow.
- 5) Cleaning shall carry out as the below items to avoid keeping solvent, solder and flux on the device.

(1) Solvent cleaning: Solvent temperature 45 °C or less Immersion for 3 min or less

- (2) Ultrasonic cleaning: Please don't carry out ultrasonic cleaning.
- (3) The cleaning shall be carried out with solvent below.

Solvent: Ethyl alcohol, Methyl alcohol

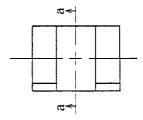
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2. Outline Dimensions (Drawing No. CY7551i02)

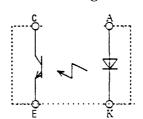
Scale: 5/1

unit: 1/1mm

Top View



Circuit diagram: Top View

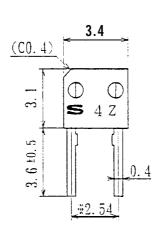


A: Anode

K: Cathode C: Collector

E: Emitter

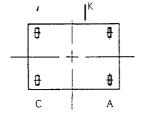
4.5 2.0 Center of light path (C 0.3)<u>0.15</u>-0.2 ± 3. 55 T





(0.3) Slit width

- 1) Unspecified tolerance shall be ± 0.2 .
- 2) Dimensions in parenthesis are shown for reference.
- 3) The dimensions indicated by x refer to the those measured from the lead base.
- 4) The dimensions shown do not include those of burrs Burr's dimensions shall be 0.15 MAX...
- 5) The marking specifications are shown below,



Z Production month: 1 to 9; Jan. to Sep.

X; Oct., Y; Nov., Z; Dec.

Production year : Last digit of the year

Sharp mark

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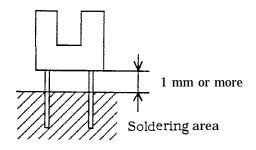
3. Ratings and characteristics

3.1 Absolute maximum ratings

Ta=25℃

Parameter		Symbol	Rating	unit
	Forward current	I_{F}	50	mA
Input	Reverse voltage	V_R	6	v
	Power dissipation	P	75	mW
	CoHector-emitter voltage	v _{CEO}	35	v
output	Emitter-collector voltage	v _{ECO}	6	v
Collector current		Ic	20	mA
Collector power dissipation		Pc	75	mW
Total power dissipation		Ptot	100	mW
Operating temperature		Topr	-25 to +85	Ç
Storage temperature		Tstg	-40 to +100	'c
* Soldering temperature		Tsol	260	Ç

* Soldering time :5 s or less



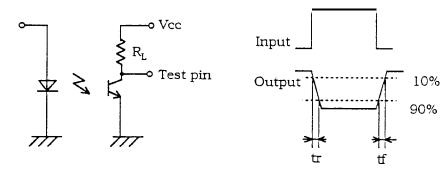
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3.2 Electro-optical characteristics

Ta=25°C

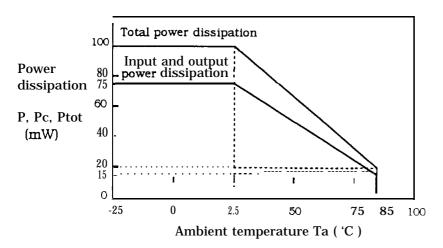
Parameter		Symbol	Conditions	MN.	TYP.	MAX.	unit	
Innut	Forward voltage		$V_{\mathtt{F}}$	I _F =20mA		1.2	1.4	V
Input Reverse current		I_R	V _R =3V			10	μA	
output	Collector dark current		I _{CEO}	V _{CE} =20V			100	nA
	Collector current		Ic	V_{CE} =5V, I_F =5mA	100	-	400	μA
Transfer character-	Dognongo	(Rise)	tr	V_{CE} =5V, Ic= 100 μ A R _t = 1000 Ω	-	50	150	μS
is tics	Response time	(Fall]	tf	$R_{\rm L}$ = 1000 Ω		50	150	μS
	Collector-emitte saturation volta		V _{CE} (sat)	$I_F = 1 \text{ OmA}$, $I_C = 40 \mu \text{ A}$	-	-	0.4	V

(Test circuit for response time)

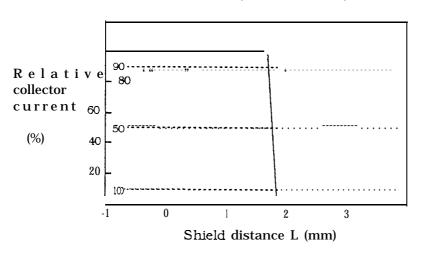


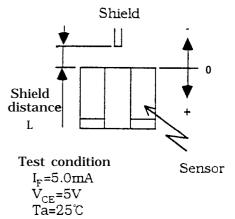
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Power dissipation vs. ambient temperature

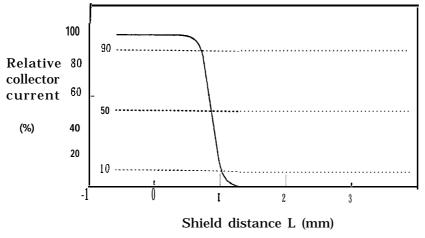


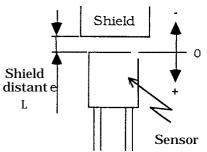
Relative collector current vs, shield distance 1 (Reference value)





Relative collector current vs. shield distance 2 (Reference value)





Test condition $I_F=5.0 \text{mA}$ $V_{CE}=5V$ $Ta=25^{\circ}C$

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4. Reliability

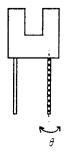
The reliability of products shall be satisfied with items listed below.

Confidence level :907. LTPD: 10%/20%

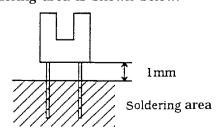
Test Items	Test Conditions	Failure Judgement Criteria	Samples (n) Defective (c)
Temperature cycling	1 cycle -40 °C to +100°C (30min) (30min) 20 cycles test		n=22, c=O
humidity storage	+60°C, 90%RH, 500h	I _R ≧U×2	n=22, c=0
High temp. storage	+100°C,500h	I _{CEO} ≧U×2	n=22, c=O
Low temp. storage	-40℃, 500 h	V _F ≧U×1.2	n=22, c=O
Operation life	I _F =20mA, Ta=25°C, 500h	Ic≦L×0.8	n=22, c=0
Mechanical shock	15000m/s ² , 0.5ms 3 times/ $\pm X$, $\pm Y$, $\pm Z$ direction		n=11, c=0
Variable frequency vibration	100 to 2000 to 100Hz/20min 2h/X, Y, Z direction 100m/s ²	U: Upper	n=11.c=0
Terminal strength (Tension)	Weight: 3N 30s / each terminal	specification limit	n=11, c=0
Terminal strength (Bending)	Weight: 1 N $0^{\text{"}} \rightarrow 90^{\circ} \rightarrow 0^{\circ}$ 2 times bending	L: Lower specification limit	n=11, c=0
Soldering heat	260°C, 5s Immerse up to 1 mm from the bottom face of package.		n=11,c=0
Solderability	230 'C, 5s Prior disposition: Dip rogin flux. Then immerse up to 1 mm from the bottom face of package.	Judgement only appearance Solder shall adhere at less than 95% area of less than of dipped portion	n=11, c=O

For details, conforms to JIS C 7021,

* Terminal bending direction is shown below.



• Soldering area is shown below.



- 5. Incoming inspection
 - 5.1 Inspection items
 - (1) Electrical characteristics

$$V_{F}$$
, I_{R} , BV_{ECO} , BV_{CEO} , Ic , I_{CEO} $V_{CE(sat)}$

- (2) Appearance
- 5.2 Sampling method and Inspection level

A single sampling plan, normal inspection level ${\rm II}$ based on ISO 2859 is applied. The AQL according to the inspection items are shown below.

Defect	Inspection item	AQL(%)
Major defect	Characteristics defect Unreadable marking	0.4
Minor defect	Appearance defect except the above mentioned.	1.0

^{*} Crack . . . Visible crack shall be defect.

* split chip

* chip Scratch The others ··· One which affects the electrical characteristics shall be defect.

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6. Supplements

6.1 Parts

This product uses the below parts.

6.1.1 Light detector (Q'ty: 1)

Туре	Material	Maximum sensitivity (nm)	Sensitivity (rim)	Response time (µs)
Phototran- sister	Silicon (Si)	930	700 to 1200	20

6.1.2 Light emitter (Q'ty: 1)

Туре	Material	Maximum light emitting wavelength (rim)	I/O Frequency (MHZ)
Infrared light emitting diode (non-coherent)	GaAs	950	0.3

6.1.3 Material

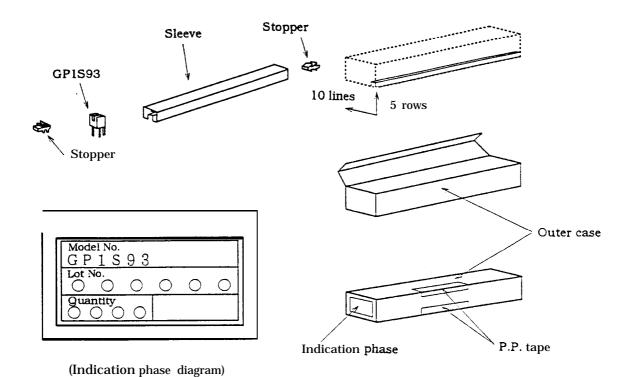
Case	Lead frame	Lead frame plating
Black PPS resin (UL 94V-0)	42 Alloy	Solder plating

6.1.4 Others

This product shall not be proof against radiation flux.

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6.2 Package (Drawing No.: SOE991548)



1) Package materials

Outer package : Outer case Inner package : Sleeve, Stopper

2) Packaging numbers

MAX. 50 pieces per sleeve MAX. 2,500 pieces per case

3) Package specifications

Arranges in 5 rows in 10 lines of sleeves containing GP 1S93 into the outer case. Closes the lid of outer case and seals with P.P. tapes.

4) Indication items

Indicates on the outer case "Model No.", "Lot No.", "Quantity" and "Inspection date".